

Toyota Technological Institute
Graduate School of Engineering

Admission Guidelines for Students of National Chung Hsing University
for Double Degree Program
<For enrollment in April 2021>

1. Admission Capacity:

Four (4)

2. Fields of Research/Education:

- Mechanical Systems Engineering
- Electronics and Information Engineering
- Materials Science and Engineering

Choose one from among the laboratories in the list attached.

3. Admission Requirements:

Applicants must be graduate students enrolled at a university with which the Double Degree Program has been established, and also must be recommended by the department chair of the home university.

4. English Skills:

Applicants are required to have a minimum of one of the followings: a TOEIC L&R or L&R IP score of 550; a TOEFL iBT score of 57; or a TOEFL ITP score of 487 at the time of the application for admission. Applications must submit the original copy of the official score report.

< Response to the covid-19 infection >

If the applicant cannot submit their TOEIC/TOEFL score report due to the influence of covid-19, he/she is required to submit an alternative document which proves their English skills are comparable to the scores listed above. The document must be written by the department chair of their home university.

5. Japanese Skills:

Applicants are expected to have Japanese skills enough to understand the courses. Classes and examinations are generally instructed in Japanese.

6. Application Procedure:

Applicants are required to submit the following documents (1)-(5):

(1) Application Form for Admission (form provided)

Prior to filling in the name of a laboratory which you hope to work in, contact the professor (who you wish to work with) and obtain the consent that you will put the laboratory name down in the application form.

※ Please check if the laboratory can accept Double Degree students or not. Some professors may not accept students in a given year.

(2) Certificate of Enrollment

Official transcripts with authorized signature or seal.

Please attach a Japanese or an English translation if the original documents are written in languages other than Japanese or English.

(3) Academic Records, Graduate and Undergraduate

Official transcripts with authorized signature or seal.

Please attach a Japanese or an English translation if the original documents are written in languages other than Japanese or English.

(4) Letter of Recommendation (form provided)

To be written by the department chair of the home university.

(5) TOEFL or TOEIC Score Record

The original copy of TOEFL Official Score Report or TOEIC Official Score report/Certificate.

※Please refer to Response to the covid-19 infection.

* A student visa needs to be ready before you enroll in the institute

7. Submission of Application Documents:

Admissions Office

Toyota Technological Institute

2-12-1 Hisakata, Tempaku-ku

Nagoya, JAPAN 468-8511

Tel : +81-52-802-1111

Fax : +81-52-809-1721

8. Application Period:

All application documents must be sent via postal mail and reach TTI no later than Tuesday, December 1, 2020.

(We do not accept the documents sent by e-mail.)

9. Selection Procedures:

Applicants will be admitted based on the submitted documents.

10. Notification of Results:

Applicants will be notified of the results of acceptance as soon as the selection has been finished.

11. Date of enrollment:

New academic year starts in April.

List of laboratories (Contact addresses for further information)

*Please add @toyota-ti.ac.jp

| | Laboratories | Name | Position | E-mail * |
|---|-------------------------------|---------------------|--------------|---------------|
| Mechanical Systems Engineering | Heat and Energy System | Keiji Takeno | Prof. | takeno |
| | Fluid Engineering | Taro Handa | Prof. | handa |
| | Solid Mechanics | Masatoshi Shimoda | Prof. | shimoda |
| | | Yoshinori Shiihara | Assoc. Prof. | shiihara |
| | Design Engineering | Masakazu Kobayashi | Assoc. Prof. | kobayashi |
| | Innovative Machine | Katsushi Furutani | Prof. | furutani |
| | Micro-Nano Mechatronics | Minoru Sasaki | Prof. | mnr-sasaki |
| Materials Processing | Masahiro Okumiya | Prof. | okumiya | |
| Electronics and Information Engineering | Semiconductor | Yoshio Ohshita | Prof. | y_ohshita |
| | Advanced Electron Devices | Naotaka Iwata | Prof. | iwata |
| | Laser Science | Takao Fuji | Prof. | fuji |
| | Memory Engineering | Hiroyuki Awano | Prof. | awano |
| | | Kenji Tanabe | Assoc. Prof. | tanabe |
| | Electromagnetic Energy System | Keisuke Fujisaki | Prof. | fujisaki |
| | Control System | Michihiro Kawanishi | Assoc. Prof. | kawa |
| | Computational Intelligence | Yutaka Sasaki | Prof. | yutaka.sasaki |
| | | Makoto Miwa | Assoc. Prof. | makoto-miwa |
| | Intelligent Information Media | Norimichi Ukita | Prof. | ukita |
| Information and Communication Engineering | Hajime Matsui | Assoc. Prof. | hmatsui | |
| Materials Science and Engineering | Optical Functional Materials | Yasutake Ohishi | Prof. | ohishi |
| | | Takenobu Suzuki | Assoc. Prof. | takenobu |
| | Frontier Materials | Kazuya Saito | Prof. | ksaito |
| | Energy Materials | Tsunehiro Takeuchi | Prof. | t_takeuchi |
| | | Masaharu Matsunami | Assoc. Prof. | matunami |
| | Theoretical Physics | Tsunehide Kuroki | Prof. | kuroki |
| | Mathematical Physics | Shinya Tomizawa | Prof. | tomizawa |
| | Quantum Interface | Itaru Kamiya | Prof. | kamiya |
| | | Akira Yamakata | Assoc. Prof. | yamakata |
| | Surface Science | Masamichi Yoshimura | Prof. | yoshi |
| | | Masanori Hara | Assoc. Prof. | haram |
| Catalytic Organic Chemistry | Yukihiro Motoyama | Prof. | motoyama | |

APPLICATION FORM

ADMISSION FOR STUDENTS OF NATIONAL CHUNG HSING UNIVERSITY

TOYOTA TECHNOLOGICAL INSTITUTE
GRADUATE SCHOOL OF ENGINEERING
DOUBLE DEGREE COURSE
<For enrollment in April 2021>

ダブルディグリー留学生入学志願書
豊田工業大学大学院工学研究科修士課程
<2021年4月入学>

Instruction 記入上の注意

1. Application documents should be written either in Japanese or in Roman block letters.
記入は日本語またはローマ字ブロック体を用いてください。
2. Numbers should be in Arabic figures.
数字は算用数字を用いてください。
3. Years should be written in the Anno Domini system.
年号はすべて西暦としてください。
4. Proper nouns should be written in full, and not be abbreviated.
固有名詞はすべて正式な名称とし、一切省略しないでください。

Attach Photo
Full Face
(4cm×3cm)
Taken within the
past 3 months

顔写真添付のこと
3ヶ月以内の撮影

1. Name : _____
氏名 Last (Family) First Middle

2. Sex : Male Female
性別 男 女

3. Date of Birth : _____ , _____ , _____ **Place of Birth :** _____
生年月日 Month Day Year 出生地

4. Nationality : _____
国籍

5. Present Address : _____
現住所

Phone : Country Code — — —
電話番号

Fax : Country Code — — —
ファックス

E-mail Address : _____
電子メール

Mailing Address : _____
書類の送付先

6. Person to be contacted in applicant's home country, in case of emergency :

緊急の際の母国の連絡先

Name : _____ **Relationship :** _____
氏名 Last (Family) First Middle 本人との関係

Address : _____
住所

Phone : Country Code — — —
電話番号

Fax : Country Code — — —
ファックス

7. Current University : _____
在籍中の大学

8. English Proficiency 英語能力 :

TOEFL Score TOEFL スコア : _____ (TOEFL iBT TOEFL ITP)

TOEIC L&R Score TOEIC L&R スコア : _____ (TOEIC L&R TOEIC L&R IP)

9. Japanese Proficiency 日本語能力 :

Excellent 優 Good 良 Fair 可 Poor 不可

10. Educational Background 学歴 :

| | ① Name of School 学校名 ② Major 専攻 ③ Location of School : Country, State, City 学校所在地 (国, 州, 市など) | Year and Month of Entrance and Completion 入学および卒業年月 | Years Required for Graduation 修学年限 |
|---------------------------------|--|--|---|
| Upper Secondary School 高校 | ① ③ | from to | |
| Undergraduate 学部 | ① ② ③ | from to | |
| Graduate 大学院 | ① ② ③ | from | |

※In case that the blank spaces above are not sufficient for information required, please accompany this form with an attached sheet.

上欄に書ききれない場合には、別紙に記入して添付すること。

11. Reason for applying to Toyota Technological Institute 本学大学院を志望した理由：

12. Preferred laboratory 志望研究室名： _____

Preferred research subject 希望する研究内容：

I certify that all information contained in this application is accurate and complete to the best of my knowledge.

この申請書の記載内容に、相違ありません。

Date : _____

日付

Applicant's Signature: _____

申請者署名

Applicant's Name (in Roman block capitals):

申請者氏名

LETTER OF RECOMMENDATION

推薦状

To the President of TOYOTA TECHNOLOGICAL INSTITUTE

豊田工業大学長 殿

Recommendee 被推薦者

Name 氏名 : _____

Date of Birth 生年月日 : _____

Nationality 国籍 : _____

I hereby recommend the person above as a qualified applicant for the double degree course of Toyota Technological Institute.

上記の者をダブルディグリープログラム派遣学生として推薦します。

Date : _____
日付 month day year

Recommender 推薦者

(The recommender must be the department chair of the home university. 推薦者は学科(専攻)長とする)

Signature : _____

署名

Name in print : _____

氏名

Title and Institution : _____

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